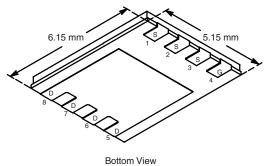


**Vishay Siliconix** 

## N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω)	I <sub>D</sub> (A) Q <sub>g</sub> (Typ			
30	0.0042 at $V_{GS}$ = 10 V	23	30.5		
	0.0059 at V <sub>GS</sub> = 4.5 V	20	30.5		





Ordering Information: Si7358ADP-T1-E3 (Lead (Pb)-free)

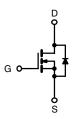
Si7358ADP-T1-GE3 (Lead (Pb)-free and Halogen-free)

### FEATURES

- Halogen-free available
- TrenchFET<sup>®</sup> Power MOSFET
- Optimized for "Low Side" Synchronous Rectifier Operation
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile
- 100 % R<sub>g</sub> Tested

## **APPLICATIONS**

- DC/DC Converters
- Synchronous Rectifiers



N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	30		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		v
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	23	14	
Continuous Drain Current $(T_j = 150 \text{ C})^{-1}$	T <sub>A</sub> = 70 °C		18	11	
Pulsed Drain Current (10 µs Pulse Width)		I <sub>DM</sub>	60		А
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	4.5	1.6	
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	50		
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	5.4	1.9	w
	T <sub>A</sub> = 70 °C		3.4	1.2	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maniana harabian ta Anabianta	t ≤ 10 s	R <sub>thJA</sub>	18	8 23	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	' 'thJA	50	65	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.0	1.5	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

# Si7358ADP

## Vishay Siliconix



Parameter Symbol		Test Conditions	Тур.	Max.	Unit		
Static			•				
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1.0		3.0	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1		
		$V_{DS}$ = 30 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C			5	μA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			А	
	Б	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 23 A		0.0032	0.0042	0	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.0045	0.0059	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 23 \text{ A}$		90		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{S} = 4.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.1	V	
Dynamic <sup>b</sup>	1. J.						
Input Capacitance	C <sub>iss</sub>			4650			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 15 V, V <sub>SS</sub> = 0 V, f = 1 kHz		880		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			390		l	
Total Gate Charge	Qg			30.5	40	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_D$ = 23 A		12.5			
Gate-Drain Charge	Q <sub>gd</sub>			10			
Gate Resistance	Rg		0.5	1.0	1.5	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			21	35		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 15 $\Omega$		10	20		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ 1 A, $V_{GEN}$ = 10 V, $R_G$ = 6 $\Omega$		83	130	ns	
Fall Time	t <sub>f</sub>			27	45		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.9 A, di/dt = 100 A/μs		50	80		

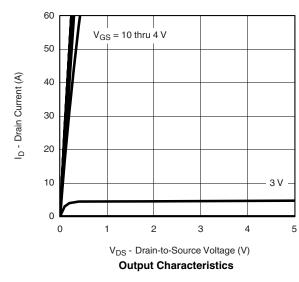
Notes:

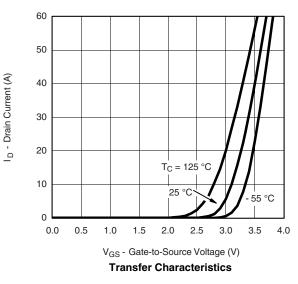
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

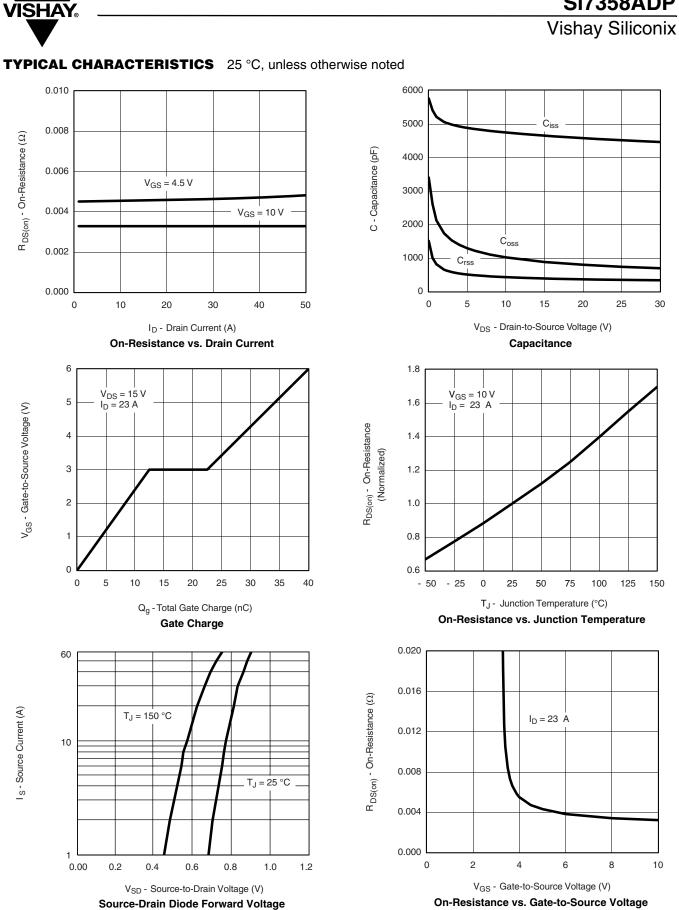
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





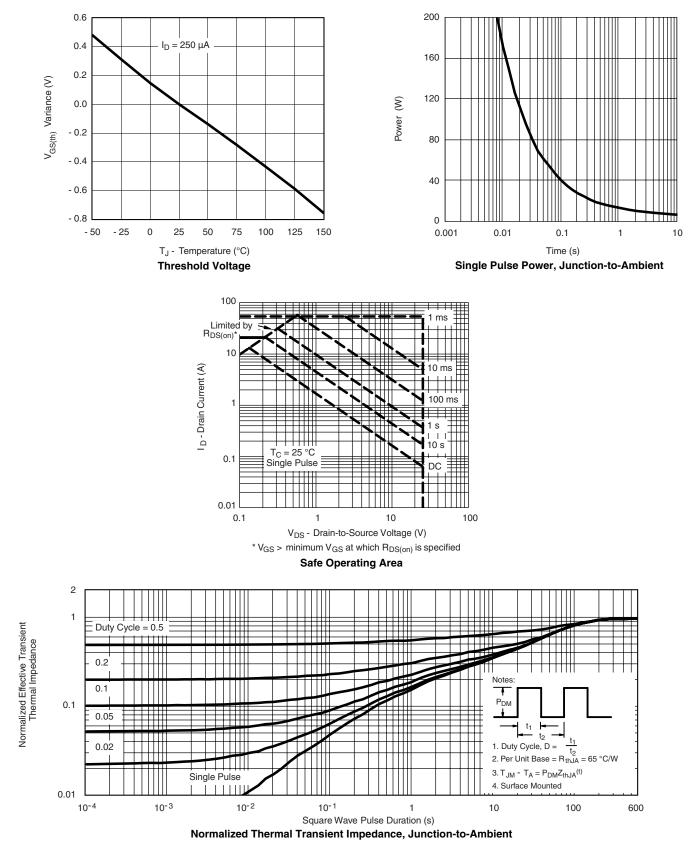


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# Si7358ADP

## **Vishay Siliconix**

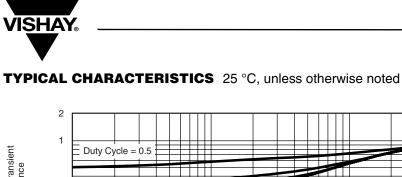
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



www.vishay.com 4







 $\mathsf{T}_{\mathsf{Super Wave Pulse Duration (s)}}^{\mathsf{T}}$ 

Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?73161.

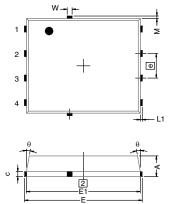
Si7358ADP

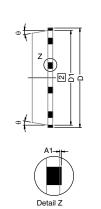
Vishay Siliconix

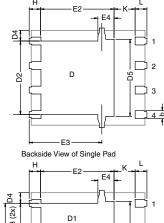


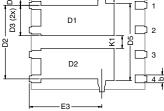
**Vishay Siliconix** 

# PowerPAK<sup>®</sup> SO-8, (Single/Dual)









Backside View of Dual Pad

Notes

1. Inch will govern.

2 Dimensions exclusive of mold gate burrs.

3. Dimensions exclusive of mold flash and cutting burrs.

	MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
A	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.56	3.76	3.91	0.140	0.148	0.154	
D3	1.32	1.50	1.68	0.052	0.059	0.066	
D4	0.57 typ.				0.0225 typ.		
D5		3.98 typ.			0.157 typ.		
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	5.79	5.89	5.99	0.228	0.232	0.236	
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144	
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151	
E3	3.68	3.78	3.91	0.145	0.149	0.154	
E4 (for AL product)		0.58 typ.		0.023 typ.			
E4 (for other product)	0.75 typ.			0.030 typ.			
е	1.27 BSC			0.050 BSC			
K (for AL product)	1.45 typ.			0.057 typ.			
K (for other product)	1.27 typ.			0.050 typ.			
K1	0.56	-	-	0.022	-	-	
Н	0.51	0.61	0.71	0.020	0.024	0.028	
L	0.51	0.61	0.71	0.020	0.024	0.028	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
М	0.125 typ.			0.005 typ.			

Revison: 20-May-13

Document Number: 71655



# Application Note 826

Vishay Siliconix

## RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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